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TABLE OF CONTENTS

Design of Short-Circuit and Overload Protection Chips for SiC MOSFETs.....	1
<i>Jiahui Lv, Yuan Yang, Minmin Zhang</i>	
Repetitive Recovery Analysis and Island Width Optimization of 4H-SiC Floating Island Devices.....	6
<i>Runze Xia, Hengyu Wang, Ce Wang, Kuang Sheng</i>	
High-Temperature Device Model for GaN-Based MIS-HEMTs.....	11
<i>Hanlin Cao, Pingyu Cao, Sang Lam, Miao Cui</i>	
Dynamic Model of Non-Segmented SiC MOSFETs Considering Switching Behavior and Temperature Effects.....	16
<i>Wenzheng Dou, Xin Lan, Ning Zhao</i>	
Investigation of the Threshold Voltage Drift in Trench-Type 1200V SiC MOSFETs Under Bipolar Dynamic Gate Stress	21
<i>Jiaying Cao, Hao Guan, Jiuyang Tang, Liudan Kong, Yifei Chang, Yuhan Duan, Qingchun Zhang, Pan Liu</i>	
Analysis of Planar and SBD-Embedded SiC MOSFET Under Avalanche Stress	26
<i>Hao Huang, Yuting Jin, Dong Hai, Dingyuan Bao, Taohui Zhang, Haoze Luo, Francesco Iannuzzo, Wuhua Li</i>	
Mechanism Analysis of Different Undamped Oscillations for GaN Devices.....	32
<i>Qiang Hu, Jian Chen, Ziyang Wang, Hao Yue, Wensheng Song</i>	
Multi-Objective Optimization for Three-Level Power Module Based on Electro-Thermal Co-Design.....	38
<i>Runze Wang, Jianing Wang, Shaolin Yu, Xing Li, Xiahao Wang, Baolong Yan, Zhenchun Xia</i>	
A Novel Zero-Pressure Packaging Structure of High-Voltage SiC IGBT Device	43
<i>Tang Xinling, Wangliang, Du Yujie, Wei Xiaoguang</i>	
Design and Characterization of a Novel Embedded SiC Power Module with Double-Sided RDL	47
<i>Yifei Du, Min Chen, Xinnan Sun, Jie Li, Yucheng Wu, Han Zhou, Feng Jiang</i>	
Low-Profile Negative Coupled Inductor for AI Chip Vertical Power Delivery Voltage Regulator	52
<i>Ruibo Cao, Xiangnan You, Fengze Hou, Na Yan, Jian Song, Qidong Wang, Liqiang Cao</i>	
Shape Optimization of High-Stress-Buffering Bridge-Typed Spacers for Double-Sided Power Modules.....	57
<i>Gaojia Zhu, Ke Xu, Bingru Li, Youzheng Wang, Longnv Li, Yun-Hui Mei</i>	
A Study of Multi-Chip Carrier Structure for SiC PCB-Embedded Power Module	62
<i>Jia-Jun Lai, Xuelun Zhang, Hao Sun, Ye Zhu, Yunbin Pan, Mingfu Li, Ziliang Shi, Xiong Yang, Xunjin Xu, Min Chen</i>	
CNN-Based Rapid Co-Optimization of BV and RON,sp for 4H-SiC SJ MOSFET.....	67
<i>Tiefu Wang, Haoyuan Cheng, Chi Zhang, Hengyu Wang, Kuang Sheng</i>	
Thermal Dissipation in GaN-On-Sapphire Power HEMTs: Synergy of Substrate Thinning and High-Conductivity Thermal Interface Materials	71
<i>Chang Liu, Junsong Jiang, Kun Tan, Jie Lu, Suxia Guo, Cungang Hu, Zhaofu Zhang, Xi Tang, Wenping Cao</i>	

Analysis of Influencing Factors on the Thermal Performance of SiC Multi-Chip Parallel Packaging Structure	77
<i>Lei Wang, Rui Jin, Xuebao Li, Peng Zhang, Chao Li</i>	
A Synchronously Implanted Termination for 1200V SiC Trench-Gate MOSFET	83
<i>Zhengyun Zhu, Jian Luo, Kai Huang, Qian Wang, Mingyang Gao, Aoxue Xu, Liang Zhou</i>	
Research on a Crosstalk Parasitic Oscillation Suppression Method Based on Series Resonance Principle	87
<i>Tiancong Shao, Pei Hu, Yuhan Sun, Kai Wang, Bin Qi, Fangwei Zhao, Zhe Zhang</i>	
Effect of Argon-Oxygen Ratios on Crystallization and Surface Morphology of Gallium Oxide Thin Films by Low-Pressure Chemical Vapor Deposition.....	91
<i>Zhihao Yang, Jichao Hu, Jinhui Yu, Xiaodong Yang, Xiaomin He, Bo Peng</i>	
Design of an Active Gate Driver IC for E-Mode GaN HEMTs Based on Adaptive Phased Regulation	95
<i>Wei Liu, Yuan Yang, Wenbin Xing</i>	
A Vertical Ultra-Thin Voltage Regulator Module (VRM) with Dual-Phase Integrated Inductor for High-Performance Computing Applications	100
<i>Nianzheng Wang, Hang Kong, Laili Wang</i>	
Design of a GaN 1-MHz/48-V-To-1-V/320-A Series-Capacitor Buck Converter	104
<i>Wendi Fan, Yanan Chen</i>	
GaN-Based Low-Voltage, High-Current DC-DC Converter for Aerospace Applications.....	109
<i>Xiao Chen, Zhihao Zhang, Zhongjie Wang, Mingming Ji, Lingxiao Xue</i>	
A New Method for Estimating the DC-DC Converter Performance Under Low Voltage and High Current Application	114
<i>Maohang Qiu, Hongbo Ma</i>	
A Totem Pole PFC Control Based on Dynamic Root Locus with Wide Output Voltage Range and Low THD	118
<i>Hao Chu, Xiangan Xiao, Xuchen Sun, Jiajia Guan, Cai Chen, Yong Kang</i>	
A SiC/Si Hybrid Pulsed Power Supply for High-Current Laser Diode Driving.....	122
<i>Yihui Tang, Xingye Chen, Yan Su, Helong Li, Zhiqing Yang, Xianbin Qi</i>	
Interleaved LLC Resonant Converter with Hybrid PSM/PFM Control for Wide Voltage Gain Applications.....	128
<i>Jintong Dong, Yijie Wang, Xiaohui Xu, Kai Ji</i>	
A Reconfigurable Half-Bridge Buck Based on Dickson SC Converter with DCX-LLC for Wide Input Voltage Range Applications	133
<i>Lichang Man, Yijie Wang, Shanshan Gao, Hongqi Ben, Dianguo Xu</i>	
Degradation Evaluation of Single-Event Effects Induced by Heavy-Ion Irradiation on E-Mode p-GaN Gate HEMT Devices.....	138
<i>Yijie Cheng, Zhangzhe Yan, Jianjun Zhou, Denggui Wang, Zhuangzhuang Hu, Hongfei Wu, Haifeng Cheng</i>	
Development of a High-Power-Density SiC Module	142
<i>Jiajun Yang, Xiaoshuang Hui, Puqi Ning</i>	

Minimizing Sensor Usage in TSEPs-Based Junction Temperature Estimation of SiC Power Transistor Through Time-Series Analysis	147
<i>Valentyna Afanassenko, Oleksandr Solomakha, Kevin Muñoz Barón, Ingmar Kallfass</i>	
Molecular Dynamics Simulations of AgCu Core-Shell Nanoparticle Sintered with Nanoflake	151
<i>Yifeng Chen, Xin Lan, Ziyang Zhang, Xin Li</i>	
The Impact of Power Module Layout on Stray Inductance	156
<i>Yuhui Kang, Puqi Ning, Xiaoshuang Hui, Jiajun Yang</i>	
Cu/Diamond Composite Electrodes for Low Thermal Resistance Packaging in High-Power IGBTs.....	160
<i>Tang Xinling, Wei Xiaoguang, Lin Zhongkang, Yang Guang, Yu Kefan, Wang Jingfei</i>	
1200V SiC MOSFETs Under Dynamic Reverse Bias Testing in High-Temperature and High-Frequency Environments.....	164
<i>Liudan Kong, Jiuyang Tang, Jiaying Cao, Yifei Chang, Hao Guan, Yuhan Duan, Qingchun Zhang, Pan Liu</i>	
Investigation of Electrical Property and Reliability in AlGaN/GaN MIS-HEMTs Fabricated by Using N ₂ /O ₂ Composite Plasma Treatment.....	169
<i>Qingyuan Zuo, Huolin Huang, Yun Lei, Jiayu Zhang, Jianyu Zhao, Jianxun Dai</i>	
Investigation on Surge Current Failure in 1200V SiC MOSFETs with Varied Gate Biases in the Third Quadrant	173
<i>Chengyuan Zhou, Hengyu Wang, Yang Zou, Kuang Sheng</i>	
Study on SiC Power Module Cooling Technologies Suitable for High-Junction-Temperature and High-Power-Density Applications.....	177
<i>Baihan Liu, Jianwei Lv, Yipeng Liu, Yifan Zhang, Siqi Dai, Zexiang Zheng, Suhang Wei, Cai Chen, Yong Kang</i>	
An Enhanced Over-Current Fault Detection System for a 7.2kV Power Module Using Series-Connected SiC MOSFETs.....	181
<i>Chunhao Hou, An Lou, Yue Wu, Aozu Luan, Shuai Shao</i>	
Modeling of Static Current Sharing of Direct-Paralleled 1.7kV 800A SiC Power Modules	186
<i>Zhongjie Wang, Hui Liao, Lingxiao Xue, Xiangqian Zhang, Liwen Zou, Xiaonan Dong</i>	
A 500W 13.56 MHz Amplifier Realized by Two Combining Class-E Circuits.....	190
<i>Yanfei Ji, Mei Liang, Jiwen Chen, Pengyu Jia, Yihang Zhang</i>	
A Method to Enlarge the Soft-Switching Range for the Dual Active Bridge Series Resonant Converter.....	195
<i>Pengyu Jia, Yimei Xing, Kai Qiu, Mingjun Liu</i>	
Bidirectional Energy-Storage Converter Based on Partial Power Processing	201
<i>Zhihao Zhang, Xiao Chen, Fan Zhai, Zhongjie Wang, Lingxiao Xue</i>	
3kV/42kW Pump-Back Test for Medium Voltage DC Transformer with Series-Connected SiC MOSFETs.....	206
<i>Yujian Zong, Shuai Shao, Chaojun Wang, Wentao Cui, Junming Zhang</i>	
Thermal Network of Double-Sided Cooling Power Module Based on Cauer Model	211
<i>Jie Li, Min Chen, Xinnan Sun, Jun Huang, Yucheng Wu, Yifei Du, Han Zhou, Feng Jiang</i>	

Multi-Objective Automatic Design of Power Module Packaging Based on Artificial Neural Network and Deep Reinforcement Learning	215
<i>Weina Mao, Jianing Wang, Shaolin Yu, Zhenchun Xia, Honghong Li, Xiang Pan, Xiahao Wang</i>	
A High-Performance Double-Sided Cooling SiC Power Module Packaging Design for EV Inverters.....	221
<i>Haobin Chen, Haidong Yan, Maosheng Zhang, Ji Cheng, Yakun Zhang, Chaohui Liu</i>	
Optimal Design of High-Temperature SiC Power Module Based on Gene Algorithm	226
<i>Zhenchun Xia, Jianing Wang, Shaolin Yu, Weina Mao, Xiahao Wang, Honghong Li, Runze Wang</i>	
Monolithically Integrated Over-Temperature Protection Circuit Based on GaN HEMTs	232
<i>Pingyu Cao, Kepeng Zhao, Yihao Xu, Harm Van Zalinge, Ping Zhang, Miao Cui, Fei Xue</i>	
Lifetime Modeling of IGBT Devices Based on Micro-Defect Topography Inversion	236
<i>Miaomiao Shangguan, Wei Lai, Hao Wang, Yunjie Wu, Yu Liu, Hang Zhao</i>	
A 6.78-MHz 2.3-KW Full-Bridge GaN Inverter with Bottom-Side Cooled Transistor GS-065-030-2-L for Wireless Power Transfer.....	241
<i>Jianping Ning, Zhen Sun, Yao Wang, Shuang Zhao</i>	
Two-Step Turn-Off Delay Time Control for Efficiency Enhancement in Si/SiC Hybrid Switch-Based Inverters	246
<i>Zijie Zheng, Jun Wang, Xuanting Song, Yongzhou Zou, Yuxing Dai, Kamal Al-Haddad</i>	
6.78 MHz 2.8 kW Resonant DC-DC Power Conversion Utilizing 650 V GaN HEMT-Based H-Bridge Inverter	250
<i>Zhen Sun, Jianping Ning, Yao Wang, Yun Yang</i>	
A Passive Cancellation Circuit Incorporating the Motor Stator Windings for Reducing the Common-Mode Noise in Motor Drive Systems	255
<i>Lihong Xie, Yuzhen Wu, Xinbo Ruan</i>	
A Voltage-Sharing Cascode Switch Structure Using SiC JFET and GaN HEMT	260
<i>Yin Fang, Shan Jayamaha, Carl Ngai Man Ho</i>	
CLLLC Resonant Converter with Full-Bridge Half-Bridge Switching for Improved Voltage Gain Range and Light-Load Efficiency	264
<i>Jinfeng Yu, Sinuo Liu, Yu Gu, Hui Liu</i>	
Analysis and Prediction Method of Gate Voltage Peak in Switching Transient of GaN E-HEMT	269
<i>Yushan Liu, Yirui Hu, Xiao Li</i>	
An Active Gate Charge Controlled Driver for SiC MOSFET with Zero Turn-Off Loss	275
<i>Yuze Zheng, Xu Cheng, Fan Zhang, Xiaolu Zhang, Yukun Niu, Xuhui Song</i>	
A Modulation Optimization Strategy for Phase Shift Full Bridge with Low Freewheeling Loss	280
<i>Enyou Wu, Xuchen Sun, Jiajia Guan, Siyuan Feng, Tianxi Li, Cai Chen, Yong Kang</i>	
Optimized Trajectory Control for Soft Start-Up of Multiple-Mode Resonant Switched Capacitor Converter.....	284
<i>Jingjing Qi, Kai Zhang, Haining Zhang</i>	
Datasheet-Driven Non-Segmented SPICE Model of SiC MOSFET with Improved Accuracy.....	290
<i>Ziqi Jia, Yu Jiang, Yifan Hu, Hailong He, Chunping Niu, Yi Wu</i>	

Investigation and Improvement on Surge Robustness of Double-Trench SiC MOSFETs in Synchronous Rectification Mode	295
<i>Hexin Zhu, Xiaochuan Deng, Haohao Dai, Qian Huang, Xuan Li, Xu Li</i>	
A High-Output-Current Radiation Hardened Half Bridge DC-DC Converter for Space Applications	299
<i>Dawei Li, Xiang Zhou, Yeerzhati Nuerdebieke</i>	
The Thermal Simulation Study of DC-DC Converters Based on Phase Change Cooling.....	304
<i>Boyang Liu, Haoyu Zhang, Yu Han, Jialiang Chi, Yao Zhao, Zhiqiang Wang</i>	
A 2:1 Capacitive Isolated Resonant Switched-Capacitor DC-DC Converter	308
<i>Xinyu Zhang, Yu Fu, Yucheng Zhao, Shouxiang Li</i>	
An Auxiliary Power Supply Utilizing Planar Winding Transformer with High Insulation and Low Coupling Capacitance Considerations.....	314
<i>Yong Chen, Xuhui Song, Fan Zhang, Yuze Zheng, Xiaolu Zhang, Yukun Niu, Zheyuan Yu, Min Wu, Kaixiang Gong</i>	
Gate-Source Voltage Oscillation of Multi-Chip SiC Power Modules Considering Differential Gate Resistance.....	319
<i>Longnv Li, Chuyuan Liu, Lu Wang, Youzheng Wang, Gaojia Zhu, Yun-Hui Mei</i>	
Development and Electrical Characteristics Study of a 10kV/125A SiC MOSFET Module	324
<i>Yaodong Zhang, Yong Chen, Xu Cheng, Xiaotian Zhang</i>	
Study of Thermal Stress on Devices in Si/SiC Hybrid Half-Bridge Inverter	328
<i>Yulin Wang, Ruixiao Dong, Jun Wang, Yuxing Dai, Liuchen Chang</i>	
A 8:1 Multi-Resonant Switched-Capacitor Converter.....	334
<i>Yuxin Yan, Yu Fu, Yucheng Zhao, Shouxiang Li</i>	
Sustainability of Power Devices: A Perspective on Design for Recycling	339
<i>Jinpeng Cheng, Shuyu Liu, Hao Feng, Li Ran</i>	
Cryogenic Output Capacitance Loss of GaN HD-GIT	343
<i>Yudong Wang, Zilong Chen, Yukun Zhang, Chong Dou, Qian Cui, Yuqi Wei</i>	
Improved Control Strategy Based on BM Theory for Grid Forming Type VSG System.....	349
<i>Shuanglong Li, Yajing Zhang, Bin Liu, Baoying Huang, Siyu Pan, Hao Ma</i>	
Baseplate Temperature Gradient-Based Health Status Monitoring for Power Module Bonding Wires	355
<i>Yongxin Chen, Lei Xu, Kun Tan, Xi Tang, Cungang Hu, Wenping Cao</i>	
Study on Influencing Factors and Mechanisms of Single-Event Gate Rupture in SiC STP-MOSFETs.....	361
<i>Ying Yang, Zixuan Liu, Chen Wang, Xulong Wang</i>	
SiC Power Module with Staggered Terminals Layout Design to Reduce Parasitic Inductance	366
<i>Jiahang Wang Guangzhou, Xi Jiang Guangzhou, Runze Ouyang, Song Yuan, Yuanzhi Zhao, Qingrong Hu, Ying Wang, Xiaowu Gong</i>	
Novel Tri-Gate Multichannel Device for Improved Vth Controllability	371
<i>Quanbo He, Hengyu Wang, Florin Udrea</i>	
Linear-ESO Based Control for Wide Input Range Partial Power Regulated DCDC Converter	376
<i>Xikun Sang, Shanshan Gao, Yijie Wang, Dianguo Xu</i>	

A Multi-Objective Optimization Method Based on NSGA-II Algorithm for Electro-Thermal-Stress Collaborative Design of Intelligent Power Modules	382
<i>Tao Xu, Lei Ming, Ningbo Li, Zihang Gu, Zhiwei Jiao, Zhen Xin</i>	
GaN-Based Partial Power DC-DC Converter with Four-Quadrant Operation Capability.....	388
<i>Chao Liu, Zhe Zhang, Shunqing Wu, Zeqi Yang, Chuang Liu</i>	
UIS Ruggedness of Si/SiC Hybrid Switches	393
<i>Chuanqi Zhang, Xuanting Song, Shiwei Liang, Yuxing Dai, Jun Wang, Kamal Al-Haddad</i>	
Research on Thermal Conductivity and Mechanical Properties Control of Epoxy Resin in Extreme Environments.....	398
<i>Zhen Li, Liang Zou, Qingsong Liu, Zhiyun Han, Jinyang Bai</i>	
A 3L-ANPC SiC MOSFET Power Module with Low Thermal Coupling and Parasitic Inductance.....	404
<i>Zedong Xue, Zhiyuan Qi, Zihao Chen, Hao Yuan, Qingwen Song, Yuming Zhang</i>	
Research on Transient Electric Field Calculation in Welded Devices Considering Dielectric Relaxation of Insulating Materials	410
<i>Zihan Sang, Zhaocheng Liu, Hao Li, Xuebao Li, Ying Cao, Peng Shu</i>	
A Two-Stage Turn-On Gate Driver for SiC MOSFET with Short-Circuit Current Suppression.....	416
<i>Yong Chen, Xiaolu Zhang, Xu Cheng, Yuze Zheng, Xuhui Song, Yukun Niu, Kaixiang Gong, Fan Zhang</i>	
A Zero-Sequence Injection Method to Reduce Electromagnetic Interference.....	420
<i>Hui Liu, Dong Jiang, Junzhao Zhang</i>	
Development of a Novel Analytical Trapped Charge Model for Total Ionizing Dose Effects of SiC MOSFETs.....	424
<i>Qingmao Hu, Xin Yang, Qingzhong Gui</i>	
Method for Estimating Power Loss of IGBT Module in Wind Power Converter Based on Measured Temperature Information.....	430
<i>Ye Tian, Dawei Chen, Zhijie Zeng, Lixuan Zhu, Guojun Bao, Zhixiang Zou</i>	
A Method for Enhancing the Heat Dissipation Performance of Power Devices Through Graphene Coating	436
<i>Xin Li, Jianing Wang, Shaolin Yu, Runze Wang, Xiahao Wang, Baolong Yan, Zhenchun Xia</i>	
Research on DC Characteristics of β -(Al _{0.22} Ga _{0.78}) ₂ O ₃ / β -Ga ₂ O ₃ Modfet	440
<i>Haitao Zhang, Xiaomin He</i>	
A Structure-Reconfigurable Electronic Transformer for Renewable Energy DC Distribution System.....	445
<i>Yu Feng, Xianbin Qi, Zhiqing Yang, Jinxiao Wei, Peng Qin, Helong Li, Liu Fang, Lijian Ding</i>	
Pyrolysis Process Analysis of Polyimide at High Temperature Based on Molecular Dynamics Simulation	450
<i>Yuteng Jiang, Minglei Xie, Wenzhi He, Zhi Wang, Bingxin Chen, Zhiyun Han, Sixiao Xin, Liang Zou</i>	
Analysis of SiC Output Capacitance Effects on Soft-Switching Characteristics in Three-Level Resonant Converters.....	456
<i>Zhe Shao, Zhiyuan Wang, Binbin Li</i>	

On the First Demonstration and Analysis of the HTGB Induced Electrical Degradation of High Voltage SiC IGBT Devices	462
<i>Tuanzhuang Wu, Jiaxing Wei, Junhou Cao, Hao Fu, Zhaoxiang Wei, Desheng Ding, Siyang Liu, Weifeng Sun, Xiaolei Yang, Song Bai</i>	
A New Si/SiC Hybrid Interleaved Three-Level ANPC Inverter with Cost and Performance Tradeoff	468
<i>Ruixiao Dong, Jun Wang, Yulin Wang, Yuxing Dai, Liuchen Chang, Chao Zhang</i>	
Turn-Off Analysis and Modeling of Releasing Loss in Snubber Capacitor Self-Balancing Circuits for Series-Connected SiC MOSFETs Applied to High-Voltage Pulsed Power Systems	474
<i>Jiaxuan Niu, Xu Cheng, Xu Yang, Yong Chen, Fan Zhang, Kexin Zhao</i>	
Optimization and Compensation of Leakage-Induced Deviation of CTTC Magnetic Integrated Structure in CLLC Resonant Converter	480
<i>Liwen Jia, Bodong Li, Yahong Yang, Jianyu Lan, Jiarui Zhang, Kelin Chen, Feng Jiang, Min Chen</i>	
Sustained Oscillation Characterization of GaN HEMT at Cryogenic Temperature.....	485
<i>Zilong Chen, Yuqi Wei, Yanjie He, Yukun Zhang, Chong Dou, Qian Cui</i>	
Design of an All-SiC On-Board Auxiliary Inverter for Urban Rail Vehicles.....	491
<i>Xuefei Li, Yongang Chen, Zixiao Li, Shuiyuan He, Yuwen Qi, Lijun Diao</i>	
A Symmetrical Double-Sided Cooled SiC Power Module for Multi-Parallel Applications	495
<i>Guolian Guan, Zhiqiang Zhao, Mingzhi Zhao, Tongyu Zhang, Laili Wang, Dewen Wang</i>	
A Transistor Clamp Circuit of On-State Voltage Drop for SiC MOSFET Temperature Monitoring	500
<i>Yixiang Zhao, Hong Li, Xiaofei Hu, Kuang Zhang</i>	
A Dynamic Current Balancing Method for Multichip SiC MOSFET Modules with Separate Gate Drive Structures.....	506
<i>Zicong Li, Zenan Shi, Yifei Luo, Xin Li</i>	
A Novel Analytical Physical Model of Gate-Drain Capacitance and Output Characteristics for SiC-MOSFET	512
<i>Ze Tao, Zenan Shi, Yifei Luo, Xin Li</i>	
Reliability Analysis for 1200V SiC MOSFETs Under Repetitive Surge Current Operation with Negative Gate-Source Bias.....	516
<i>Xinbin Zhan, Yanjing He, Jiankun Lai, Xi Jiang, Song Yuan, Hao Yuan, Qingwen Song, Xiaoyan Tang, Xiaowu Gong, Yuming Zhang</i>	
A Novel Modulation Method with Simultaneous Reduction of Common-Mode Voltage and Switching Losses for Three-Level SNPC Inverter	520
<i>Shuangxi Zhu, Jiajia Guan, Cai Chen, Yong Kang</i>	
An Active Gate Driver of Voltage Overshoot Suppressing for SiC MOSFETs	524
<i>Tingwen Hu, Wensheng Song, Jian Chen, Tao Tang, Hao Yue, Guoyou Liu</i>	
A High-Frequency LLC Resonant Converter Incorporating Matrix Transformer	528
<i>Haochen Zhang, Yueshi Guan, Yijie Wang, Dianguo Xu</i>	
An Active Gate Driver Addressing GaN HEMT Gate-Source Voltage Overshoots for Both Turn-On and Turn-Off Periods	534
<i>Lurenhang Wang, Yishun Yan, Shuaiqing Zhi, Mingcheng Ma, Xizhi Sun, Dianguo Xu</i>	

Application of Wide Bandgap High Frequency Inverter in 10 kW Magnetic Field-Coupled Undersea Wireless Power Transfer Systems.....	539
<i>Lei Yang, Jiahua Sun, Yuanfeng Wang</i>	
Minimizing Eddy Current Loss for Implanted Wireless Charger Through Phase Difference Optimization.....	544
<i>Pengyu Chen, Siyi Yao, Xiyuan Lin, Hongjun Zheng, Congcong Zhang, Minfan Fu</i>	
An Accurate Leakage Inductance Model for Magnetic Integrated Planar Transformers in LLC Resonant Converters.....	550
<i>Zhili Mo, Xuetong Zhou, Yufei Tian, Li Zheng, Xinhong Cheng</i>	
Subharmonic Oscillations in High-Frequency Switched-Mode Power Amplifiers	556
<i>Wei Liu, Ming Liu</i>	
Novel Structure for High-Voltage Vertical β -Ga ₂ O ₃ Schottky Barrier Diodes: A TCAD Study.....	562
<i>Yan Liu, Meng-Qi Fan, Jia-Xiang Chen, Teng Jiao, Mao-Jin Yang, Xian-Hu Zha, Xiao-Ping Wang, Xiang-Jin Ding, Yu-Xi Wan, Dao-Hua Zhang</i>	
Efficiency-Oriented Adaptive Dead Time Control for the Dual Active Bridge Converter	566
<i>Shaoyan Jiang, Xichen Fu, Xingque Xu, Jiabin Ruan, Chuanwei Xiao</i>	
Simulation Study of Breakdown Characteristic of Vertical Diamond Schottky Barrier Diodes with Different Drift Layer Parameters and Termination Structures.....	572
<i>Tianhe Mi, Peng Wang, Yan Liu, Teng Jiao, Xinchun Cui, Haolin Hu, Yuxi Wan, Daohua Zhang</i>	
Multi-Parameter Degradation Modeling Method for Power MOSFETs Integrating Semiconductor Physics Degradation Data.....	577
<i>Chenyi Wang, Cen Chen, Weixuan Kong, Haodong Wang, Zhenning Zhou</i>	
1.5KW HSC Converter Power Density-Efficiency Advancement: Enabled by Planar Transformer.....	582
<i>Pengfei Wang, Vickie Qu, Qianru Shi, Qingchang Liu, Ian Yj Chan, Minfan Fan</i>	
Control Strategy of Dual Phase Shifting Dual Active Bridge Converter Based on BM.....	588
<i>Yiting Huo, Yajing Zhang, Bin Liu, Baoying Huang, Siyu Pan, Hao Ma</i>	
β -Type High-Gain Boost Converter with Diode-Capacitor Cell	594
<i>Peng Sun, Hong Li, Yidi Liang, Xu Shangguan, Mingbo Wei, Huizhu Zhuang</i>	
Soft-Switching Fixed-Frequency Control Strategy for Three-Level Buck-Boost Converter	600
<i>Fang Li, Yao Xue, Fangwei Zhao, Yajing Zhang, Jun Xu</i>	
High-Robust Power Integrated Synchronization Scheme for the Grid-Forming Inverter	606
<i>Wen Zou, Yuying He, Li Zhang, Dongsheng Yang</i>	
Charge Control for Critical Conduction Mode Soft-Switching Grid-Tied Inverters	609
<i>Zhengzi Lei, Zhongshu Zheng, Wenbo An, Li Zhang, Yuying He</i>	
Dynamic Analysis of Hybrid Photovoltaic-Battery System with Dual-Mode Grid-Forming Control.....	614
<i>Wenjie Ning, Yiyang Liao, Yaoyu Hu, Shaoze Zhou, Zheng Wei, Yitong Li</i>	
Optimization Design of High-Speed and High-Voltage Switching Transient Characteristics for GaN HEMTs Using Multi-Objective Particle Swarm Optimization.....	619
<i>Xiao Li, Zhuofan Xiong, Yushan Liu, Qiang Zhou</i>	

A Compact EMI Filter Design Method Based on Chaotic SVPWM in Motor Drive System	624
<i>Yanjun Li, Hong Li, Zuoxing Wang, Aojie Liao, Mingxin Shi</i>	
A SiC MOSFET Accelerated Degradation Test Platform that Accounts for Turn-On and Turn-Off Times	630
<i>Bohang Lu, Cen Chen, Zicheng Wang, Xuanyu Lin</i>	
Bias Temperature Instability of SiC Trench MOSFET Under DC and AC Gate Stress.....	634
<i>Kanghua Yu, Qian Wang, Yuwei Wang, Jun Wang</i>	
A Novel Approach to Estimate the Thermal Destruction Point of SiC MOSFETs Under Short Circuit Conditions	638
<i>Rony Thomas, Zhe Yu, Sebastian Fahlbusch</i>	
Investigation on Electrical Properties and Safe-Operating Area for Novel Split-Gate IGBTs	644
<i>Xuanting Song, Jun Wang, Gaoqiang Deng, Zijie Zheng, Yongzhou Zou, Shiwei Liang, Yuxing Dai, Kamal Al-Haddad</i>	
Influencing Factors and Mechanisms of Single-Event Burnout in STP SiC MOSFETs	649
<i>Ying Yang, Xulong Wang, Chen Wang, Zixuan Liu</i>	
A Multi-Operation Characterization System for Quantifying Dynamic RON Degradation in p-GaN Gate GaN HEMTs Under Real-World Switching Conditions.....	655
<i>Junbo Wang, Xiangdong Li, Xi Jiang, Haonan Jiang, Shuzhen You, Yue Hao, Jincheng Zhang</i>	
The Establishment of Quasi-3D TCAD Simulation for Bipolar Degradation Occurs in SiC MOSFET Body Diode.....	659
<i>Junhou Cao, Xinyu Zhou, Chenlu Wang, Lei Huang, Hao Fu, Zhaoxiang Wei, Tuanzhuang Wu, Jiaying Wei, Siyang Liu, Weifeng Sun</i>	
Study on AlxGa1-xN Graded Composite Barrier GaN HEMT	663
<i>Ruihao Zhang, Fayu Wan</i>	
Chip Screening Strategy for SiC MOSFET Based on Simulated Annealing Algorithm.....	667
<i>Zhanshan Zhu, Chuangye Li, Helong Li, Zhiqiang Liu, Lijian Ding</i>	
Research on Power Loss Calculation and Optimization of FB-VSCC Active EMI Filter.....	673
<i>Daozhen He, Hong Li, Yuanheng He, Mingxin Shi</i>	
Analysis of Common-Mode EMI in Multi-Converter Systems with EMI Filters	678
<i>Runquan Jiang, Peng Zhou, Guifeng Geng, Xuejun Pei</i>	
Research on Key Technology of Low Noise Transformer and Its Application on 110kV Transformer	684
<i>Shouhui Han, Qingsong Liu, Zheng Liu, Liang Zou, Zhiyun Han</i>	
Study on Cross-Scale Collaborative Control of Composite Properties for Power Device Packaging.....	688
<i>Xianfeng Li, Jian Wang, Hanwen Ren, Wei Wang, Chen Chen, Qingmin Li</i>	
Partial Discharge Denoising Technology for GIS Equipment Based on CEEMDAN	692
<i>Zhongyue Liu, Pei Cao, Zeyu Li, Hanwen Ren</i>	
Improvement of Thermal Conductivity of Epoxy Composites Using the Synergistic Effect of Boron Nitride Nanosheets and Boron Nitride Whiskers	696
<i>Tiandong Zhang, Chenghai Wang, Xinle Zhang, Tangman Xue, Changhai Zhang, Qingguo Chi</i>	

Study on Surface Discharge Characteristics of Silicone Gel in Salt Fog Environment.....	700
<i>Feng Wang, Zihui Li, Yateng Yany, Shanzhen Fan, Hanwen Ren, Jian Wang, Wei Wang, Qingmin Li</i>	
Effect of Atomic-Level Roughness on Vertical β -Ga ₂ O ₃ Schottky Barrier Diode and High-Temperature Performance.....	704
<i>Jiaxiang Chen, Xingye Zhang, Maojin Yang, Xinpeng Lin, Teng Jiao, Yan Liu, Xianhu Zha, Haolin Hu, Xiangjin Ding, Yuxi Wan, Jun Ma, Mengyuan Hua, Dao-Hua Zhang</i>	
U-Shaped Sloped Field Plate Edge Termination Structure in β -Ga ₂ O ₃ Vertical SBD.....	709
<i>Yanzuo Li, Song Yuan, Xi Jiang, Yanjing He, An Xu, Guorui Mo, Yunxuan Zhao, Zhaoheng Yan, Qifan Liu, Xinbin Zhan, Ying Wang, Linhai Zhong, Xiaowu Gong</i>	
Enhancement-Mode Vertical (001) β -Ga ₂ O ₃ Power Transistor Enabled by Dual Ion Implantation.....	713
<i>Anjing Luo, Gaofu Guo, Li Zhang, Tiwei Chen, Dengrui Zhao, Zhili Zou, Chunhong Zeng, Huanyu Zhang, Baoshun Zhang, Zhucheng Li, Xiaodong Zhang, Zhongming Zeng</i>	
Partial Discharge Classification and Intelligent Maintenance Decision-Making Based on Spikingformer and LLMs.....	717
<i>Changdong Wang, Jingli Yang, Xunran Yin, Shuangyan Yin, Tianyu Gao, Yongqi Chang, Huamin Jie, Zhou Shu, Zhenyu Zhao</i>	
Junction Temperature Fluctuation Suppression Strategy for SiC MOSFETs Based on Equivalent Gate Resistance Control.....	721
<i>Ruoyin Wang, Xiaoyong Zhu, Hong Zheng</i>	
Study of a High-Sensitivity Recessed-Anode GaN MIS Diode for Temperature Sensing.....	726
<i>Yunxuan Zhao, Xi Jiang, Song Yuan, Zhaoheng Yan, Yanzuo Li, Chaofan Deng, Xiangdong Li, Xiaowu Gong</i>	
Warping Model of SiC Power Module After Reflow Soldering.....	731
<i>Chang Liu, Yingxin Cui, Yanao Guo, Shoulai Gong, Jisheng Han</i>	
A Novel Mechanical Stress Related Failure Mechanism of the State-Of-The-Art SiC Double Trench MOSFET Under Surge Current Stress.....	737
<i>Shikang Xu, Xuan Li, Hanqing Zhao, Yi Wen, Wensong Peng, Zekun Zhou, Xu Li, Xiaochuan Deng, Bo Zhang</i>	
Impact of Elevated Humidity Conditions on the Thermal and Mechanical Reliability of Silicon Carbide MOSFETs.....	741
<i>Jiayu Zhang, Dong Xie, Zhiliang Xu, Zepeng Jiang, Xinglai Ge</i>	
Reliability Analysis and Implementation of Silver Sintering Connection in SiC High-Temperature Package.....	747
<i>Zizhen Cheng, Wenjie Xu, Fengtao Yang, Zhiqiang Zhao, Dewen Wang, Laili Wang</i>	
Impact of Kelvin Source Connection (KSC) Vs. Common Source Connection (CSC) on Power Cycling Aging Characteristics of Silicon Carbide (SiC) MOSFETs.....	753
<i>Huaihao Cheng, Yong Chen, Xu Cheng, Xingyu Pei, Jianbiao Li, Hongyuan Wu</i>	
SiC VDMOSFET Performance Prediction Method Based on Neural Network.....	757
<i>Xiamin Hao, Feng He, Rui Jin</i>	
Oxidation-Free Sintered Copper Die Attachment for Power Electronics Packaging.....	762
<i>Junyang Chen, Haiqiang Zhao, Zewei Zhang, Zhuo Pang, Tsung-Huan Sheng, Yi Chiu, Zhi-Ying Huang, Yen-Liang Lin, Meiyu Wang</i>	

Advanced Packaging for High-Voltage SiC Module with Excellent Thermal, Mechanical, and Electrical Properties.....	767
<i>Meiyu Wang, Yiting Han, Peng Gao, Zhuo Pang, Yingkun Yang, Haidong Yan</i>	
A One-Inductor Two-Switch Three-Port DC-DC Converter for PV-Battery Systems.....	772
<i>Yidi Liang, Hong Li, Huizhu Zhuang, Peng Sun, Xu Shangguan</i>	
A Parameter Design Method for Bidirectional LLC-C Resonant Converter for Bidirectional On-Board EV Charger Application.....	777
<i>Yiheng Zhang, Pengyu Jia, Mingjun Liu, Yimei Xing</i>	
A Phase Shift Control Strategy for the DCX to Realize a Wide Voltage Range by a Variable Mode Transformer	783
<i>Pengyu Jia, Mingjun Liu, Yimei Xing</i>	
A Multi-Port Converter-Based Equalization Architecture with Wide Voltage Gain for Long Series Battery Packs.....	788
<i>Haipeng Hu, Xianbin Qi, Helong Li, Mingzhu Fang, Peng Qin, Zhiqing Yang, Lijian Ding</i>	
Design of Planar Integrated Transformer for LLC Resonant Converters Based on Hybrid Magnetic Materials.....	792
<i>Jianguang Yao, Xiaoyi Xu, Yanfang Mao, Zhujian Ou, Runyang Ji</i>	
Common-Mode Noise Analysis of Hall-Effect Sensor for SiC Power Converter	798
<i>Guifeng Geng, Peng Zhou, Runquan Jiang, Xuejun Pei</i>	
Research on Online Reliability Assessment Technology for IGBT Based on Driver-Side Measurement Fusion	802
<i>Yi Liu, Zhicheng Liu, Yunhui Mei</i>	
An Active Current Sharing Strategy Based on Master-Slave Cooperative Control for Paralleled SiC Power Modules.....	808
<i>Baolong Yan, Jianing Wang, Shaolin Yu, Honghong Li, Runze Wang, Xin Li</i>	
Investigation on SiO ₂ Gate Formed Through Ultrahigh-Temperature NO Oxidation	813
<i>Yingfeng He, Given Shucheng Chang, Decai Liu, Tao Zhu, Zheyang Li, Rui Jin</i>	
The Method for Chip Sorting Based on SiC MOSFET Parameters for Parallel Current Sharing Under a Symmetrical Layout.....	817
<i>Yi Li, Bowen Tian, Bin Zhao, Peng Sun, Zhibin Zhao, Xu Cheng, Yong Chen, Xingyu Pei, Jianbiao Li, Hongyuan Wu</i>	
Charaterization of a Nonlinear Conductivity Encapsulant for Electric Field Reduction in High-Voltage Power Module Packaging.....	822
<i>Meiyu Wang, Peng Gao, Yiting Han, Haidong Yan</i>	
Configuration Selection for Degradation Trajectory Prediction of Power Modules Based LSTM Model	827
<i>Yichi Zhang, Yi Zhang, Jie Kong, Jiahong Liu, Bo Yao, Huai Wang</i>	
A Review and Analysis of Grid-Forming Technologies in Renewable Energy Power Systems.....	833
<i>Zhicheng Liu, Dezheng Zhang, Yehan Fu, Yuying He, Li Zhang</i>	
Switching Oscillation Suppression Based on Embedded SiC Power Module with Low Parasitic Inductance for CLLC Resonant Converter	839
<i>Jiarui Zhang, Bodong Li, Xinnan Sun, Jiahui Wang, Liwen Jia, Kelin Chen, Feng Jiang, Min Chen</i>	

Modeling and Design of the Planar Magnetic Integration for Dual-Stage EMI Filters.....	844
<i>Haiyan Liang, Yitao Liu, Zijian Lu</i>	
A Method to Decrease the Submodule Capacitor Voltage Fluctuations in Voltage-Source Modular Multilevel Converter with Wide-Bandgap Power Devices.....	849
<i>Qian Kang, Tiancong Shao, Trillion Zheng, Yuqing Geng, Yaqi Li, Zhitong Bai, Xiaofeng Yang</i>	
Junction Temperature Control and Thermal Stability Enhancement Method for Power Devices Based on Vapor Phase-Change Principle.....	853
<i>Ruya Song, Shuang Zhao, Jinxiao Wei, Waleed Alhosaini, Lijian Ding</i>	
A Self-Clamped L-Shaped Trench Gate SiC MOSFET with Improved Breakdown and Short-Circuit Reliability	857
<i>Xiaobo Cao, Jing Liu, Shaowei Zhang, Qian Zhang, Zhonggang Yin</i>	
Degradation of Planar-Gate SiC MOSFETs Under Repetitive Short-Circuit Stress in Different Gate Bias.....	863
<i>Yifan Wu, Chi Li, Jianwei Liu, Zedong Zheng</i>	
Low Roughness and Shape Reforming 4H-SiC Trench Process Optimized by CCP Etching with High Temperature Annealing and Sacrificial Oxidation.....	867
<i>Qiongyang Zhuang, Xixi Luo, Yu Chen, Caixin Gu, Lei Song, Kaiju Liao, Qin Hu, Jiamin Tian, Yidan Chen, Gang Chen, Jinliang He</i>	
Investigation of L-FER ESD Protection Capability on E-Mode p-GaN HEMT	873
<i>Junye Wu, Yitian Gu, Chao Feng, Danfeng Mao, Yanlin Wu, Haolin Hu, Wei Zeng, David Zhou, Yuxi Wan</i>	
Study on 4H-SiC Trench Gate Dual-Mode Composite Transistors (T-DCT) Structure to Reduce Ron and Enhance SCWT	877
<i>Wenyu Xi, Cailin Wang, Lei Guan</i>	
Super-Junction IGBT with Adaptive Hole Channel Around Stepped Trench Gate for Low On-State Voltage and Low Turn-Off Loss	881
<i>Xuele Zhou, Hengyu Wang, Yifan Wang, Kuang Sheng</i>	
Effect of Voltage Probes on the Characterisation of Switching Processes in Wide-Bandgap Semiconductor Devices	885
<i>Yishun Yan, Lurenhang Wang, Xuchong Cai, Mingcheng Ma, Yanchen Pan, Dianguo Xu</i>	
Performance Improvement of SiC n-LTT by Semi-Through Via Structure.....	890
<i>Yulei Zhang, Xi Wang, Xuhui Pu, Jichao Hu, Hongbin Pu, Yuan Yang</i>	
Comparative Investigation of Gate Oxide Degradation in 1.2 kV Planar, Double-Trench, and Asymmetric-Trench SiC MOSFETs.....	894
<i>Dingkun Zhao, Xin Yang</i>	
Understanding the Role of Buffer Traps in GaN HEMTs: A Simulation Study on Dynamic Ron	898
<i>Haiyang Li, Mengqi Fan, Xinyue Dai, Xiaoping Wang, David Zhou, Danfeng Mao, Yan Wang, Yuxi Wan</i>	
A 3×1 Silicon Carbide Bidirectional Switch Power Module with Balanced Inductance During Current Commutation.....	902
<i>Zhiwei Jiao, Lei Ming, Yufeng Cao, Tao Xu, Zihang Gu, Zhen Xin</i>	
An Experimental Study on Single Pulse Avalanche Characteristics of Si/SiC Hybrid Switch.....	907
<i>Hangzhi Liu, Yuming Zhou</i>	

Substrate Coupling Considerations for Monolithic Integration of High-Voltage Power Transistors with Low-Voltage Devices and Circuits in GaN-On-Si Technology	911
<i>Rui Ray Yao, Miao Cui, Zhao Wang, Sang Lam, Stephen Taylor</i>	
Analysis and Compensation Method of Transient Unbalanced Current in Parallel Connection of SiC MOSFET	916
<i>Yong Chen, Xu Cheng, Xingyu Pei, Jianbiao Li, Hongyuan Wu, Bin Zhao</i>	
Design and Fabrication of a SiC Trench MOSFET with Multi-Step P-Type Shielding and Multiple CSL Layers	920
<i>Wei Chen, Fei Guo, Yangyang Wu, Kuan Wang, Zhijie Cheng, Jun Yuan, Rong Zhang, Guoqing Xin, Zhiqiang Wang</i>	
A Novel Integrated Power Module Package Method with SiC MOSFETs and Energy Absorber in Solid-State Circuit Breaker Application	924
<i>Dongxin Jin, Jie Gong, Yuchen Wang, Cheng Luo, Xiaojun Dong, Guangyin Lei</i>	
Dry Oxidation and SiO ₂ Deposition Strategies for High-Performance Gate Dielectrics in 3.3 kV SiC Power MOSFETs.....	929
<i>Zijian Hu, Hongyi Xu, Na Ren, Kuang Sheng</i>	
Low Parasitic Repackaging and Integration of Multiple GaN HEMT Devices.....	933
<i>Yue Chen, Mingrui Zou, Dongjun Jiang, Senhao Liang, Jiakun Gong, Zheng Zeng</i>	
Impact of Electroluminescence Spectrum Sampling on SiC MOSFET Junction Temperature and Current Sensing	939
<i>Yuting Jin, Hao Huang, Jingyang Hu, Shengjie Luo, Haoze Luo, Wuhua Li</i>	
Research on Threshold Voltage Instability of SiC MOSFETs at High Temperature	944
<i>Xu Cheng, Yong Chen, Xingyu Pei, Jianbiao Li, Hongyuan Wu, Cong Chen</i>	
A High-Isolation X-Ray Power Supply with Multi-Transformer Series Configuration	949
<i>Ziyang An, Ye Tian, Jie Ming, Yu Dou, Chushan Li</i>	
A High-Speed Dynamic Gate Driver with Low Oscillation for GaN HEMTs	954
<i>Xuetong Zhou, Li Zheng, Xinhong Cheng, Lingyan Shen</i>	
Research on an Anti-Offset Wireless Power Transfer System with Auxiliary Resonant Circuit	959
<i>Youzheng Wang, Shengxiu Xu, Shuyu Wang, Hongchen Liu, Longnv Li, Gaojia Zhu, Yunhui Mei</i>	
Research on Low Speed Power Boosting Technology for High Speed Maglev Trains	963
<i>Zheyi Zheng, Fuaao Chen, Xiaojun Zhang, Haoyun Wang, Yang Chen, Ruikun Mai</i>	
Current Overshoot and Oscillation Suppression in SiC MOSFETs Through Variable Gate Capacitance During Turn-On Transient.....	968
<i>Xuchong Cai, Yishun Yan, Yanchen Pan, Mingcheng Ma, Binbo Xu, Dianguo Xu</i>	
An Active Clamped Resonant Ultra-High Frequency Quasi-Square Wave Gate Driver for SiC MOSFET	974
<i>Zhiqing Liang, Zhixing He, Haoyi Sheng, Renfeng Guan, Zhenyuan Ou, Yang Liu, Zongjian Li, Jun Wang</i>	
48V-To-0.9V Voltage Regulator with GaN Devices and Integrated Magnetic Design	980
<i>Zikang Li, Jingyang Tan, Yijie Wang, Dianguo Xu</i>	

A Bidirectional-Signal Transmission Method for Gate Drive Application Using Single Isolation Transformer	985
<i>Junru Lin, Junming Zhang</i>	
A Dual-Voltage 650 V and 100 V GaN Integrated Platform Featuring High-Performance Monolithic Components	990
<i>Yanlin Wu, Junye Wu, Zuoheng Jiang, Danfeng Mao, Keping Wu, Chao Feng, Jiawei Chen, David Zhou, Yuxi Wan</i>	
Exploring the Soft-Switching Benefits of TZCM Mode in Three-Level DC-DC Converters Using Wide Bandgap Power Devices	994
<i>Zhigang Yao, Jingrui Liu, Sankun Yao, Bac-Bien Ngo, Ziheng Xiao, Yi Tang</i>	
Design and Current-Sharing Study of the TL-Boost Power Unit Based on Discrete Devices in Parallel.....	1000
<i>Jianing Wang, Honghong Li, Shaolin Yu, Donglei Zhang, Baolong Yan, Zhenchun Xia, Weina Mao</i>	
Study on New Structures of EST to Inhibit Snapback Effect and Enhance MCC	1006
<i>Wuhua Yang, Jia Liping, Guo Jiarui, Zhang Chao, Shen Sihao, Wang Cailin</i>	
A Transient Interaction Mechanism Analysis Method for the Grid-Forming Voltage Support Device Integrated into LCC-HVDC System.....	1011
<i>Yanlin Song, Zhichang Yang, Hong Li</i>	
A Numerical Model of SiC MOSFET for Electro-Thermal Characteristics Based on TCAD	1017
<i>Yujie Zhang, Yongle Huang, Yifei Luo</i>	
The Method to Evaluate the SOA of Drain-Source Voltage for SiC MOSFET	1022
<i>Fengming Yang, Xin Li, Yifei Luo, Lin Liang, Yongle Huang</i>	
GaN-Based 1.5 MHz Synchronous Buck Converter with Partial Soft-Switching Control Scheme	1028
<i>Zeqi Yang, Yuan Liu, Zhe Zhang</i>	
Design and Demonstration of a Novel SiC Trench MOSFET with Periodically Grounded P Shield Island Based on Secondary Epitaxy Process	1033
<i>Yangyang Wu, Fei Guo, Kuan Wang, Wei Chen, Zhijie Cheng, Yuan Jun, Rong Zhang, Guoqing Xin, Zhiqiang Wang</i>	

Author Index